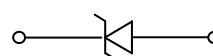


Features

- 240Watts peak pulse power ($t_p=8/20\mu s$)
- Unidirectional configuration
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line to:
- IEC 61000-4-2 $\pm 15kV$ contact $\pm 8kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 6A (8/20 μs)
- RoHS compliant



DFN1006



Schematic Diagram

Applications

- Audio Line, Speaker, Headset, Microphone Protection
- Human Interface Devices (Keyboard, Touchpad, Buttons)
- DC Power Line Protection

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Max.	Unit
Peak Pulse Power ($T_p=8/20\mu s$)	P_{PP}	240	W
ESD Contact/Air Discharge (IEC-61000-4-2)	V_{ESD}	8/15	kV
Peak Pulse Current ($t_p=8/20\mu s$)	I_{PP}	6	A
Junction Temperature	T_J	-55 To +125	$^\circ C$
Storage Temperature	T_{STG}	-55 To +150	$^\circ C$

Electrical Characteristics ($T_A=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Reverse Stand-Off Voltage	V_{RWM}	-	-	-	24	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	26.7	-	-	V
Reverse Leakage Current	I_R	$V_R=24V$	-	0.1	0.5	μA
Clamping Voltage (IEC 61000-4-5)	V_C	$I_{PP}=6A$	-	-	44	V
Junction Capacitance	C_J	$V_R=0V, f=1MHz$	-	35	40	pF

Typical Characteristic Curves

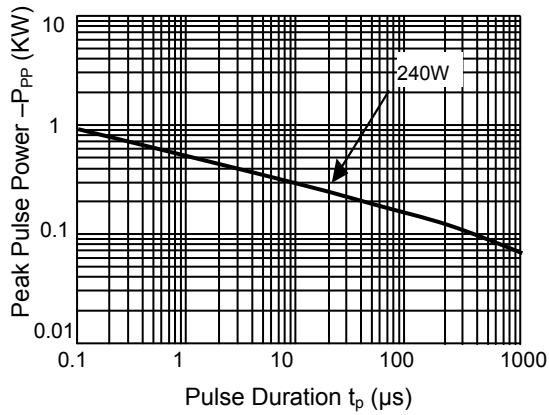


Figure 1. Peak Pulse Power Rating Curve

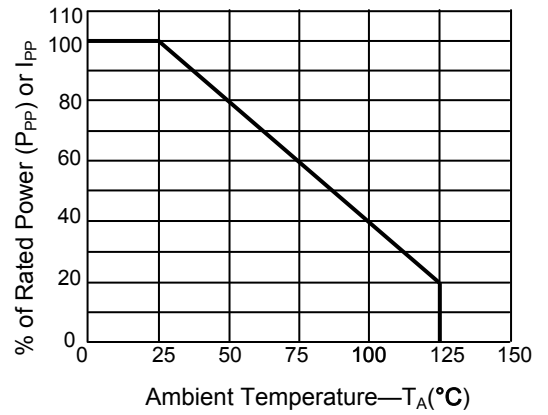


Figure 2. Pulse Derating Curve

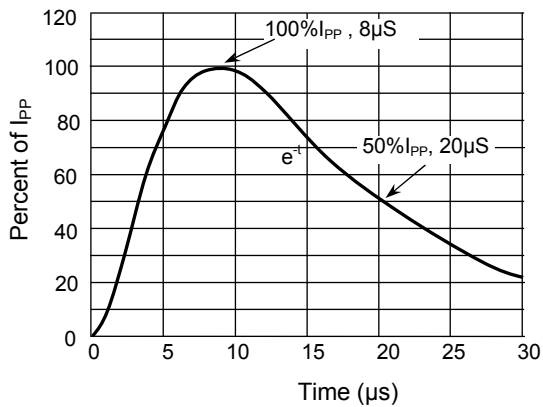


Figure 3. Pulse Waveform-8/20μs

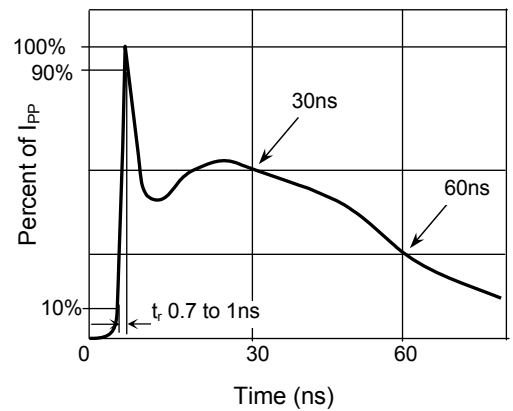
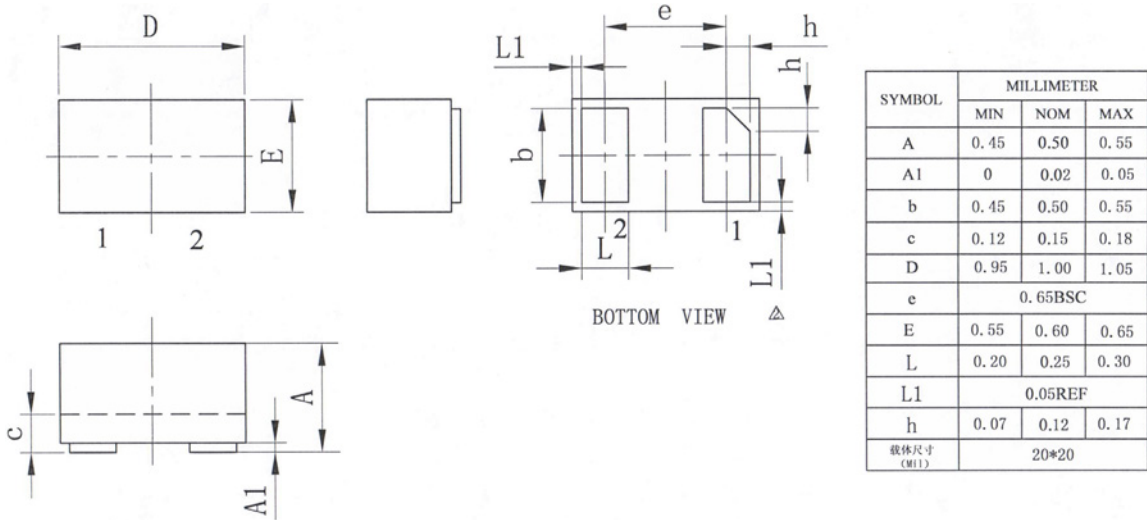


Figure 4. Pulse Waveform-ESD (IEC61000-4-2)

Package Outline Dimensions DFN1006



Order Information

Device	Package	Marking	Carrier	Quantity	HSF Status
GSEZ24U350	DFN1006	24F	Tape & Reel	10,000pcs / reel	RoHS compliant